

JC02 Rec'd PCT/PTD 29 AUG 2005 #3

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

TAUNIER ET AL.

Serial No. 10/540,731

Filed: June 24, 2005

For: **METHOD FOR REGENERATION OF AN  
ELECTROLYSIS BATH FOR THE PRODUCTION  
OF A COMPOUND I-III-VI<sub>2</sub> IN THIN LAYERS**

**INFORMATION DISCLOSURE STATEMENT**

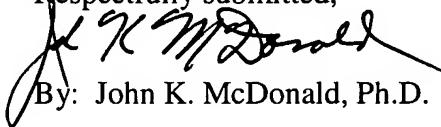
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

The citation of information on the attached Form PTO/SB/08, "Information Disclosure Statement by Applicant" is made pursuant to 37 C.F.R. §§ 1.97 and 1.98. A copy of the listed items is enclosed.

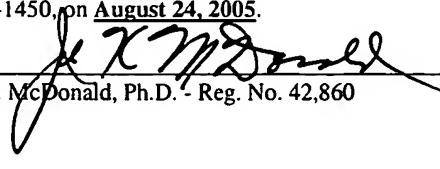
The citation of this information does not constitute an admission that any of the materials are available as a reference or of priority, or a waiver of any right applicant may have under applicable statutes, Rules of Practice in patent cases, or otherwise.

Respectfully submitted,

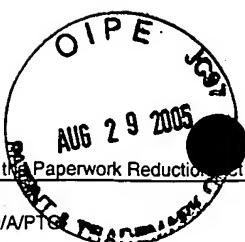
  
By: John K. McDonald, Ph.D.

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Our Docket: 16721-0280 (42528-316590)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on August 24, 2005.

  
John K. McDonald, Ph.D. - Reg. No. 42,860

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Substitute for Form 1449/A/PTO

# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

**Complete if Known**

<b>Application Number</b>	10/540,731
<b>Filing Date</b>	June 24, 2005
<b>First Named Inventor</b>	STEPHANE TAUNIER
<b>Group Art Unit</b>	
<b>Examiner Name</b>	
<b>Attorney Docket Number</b>	16721-0280 (42528-316590)

Sheet

of

**U.S. PATENT DOCUMENTS**

Examiner Initials	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			
		4,253,919		Hall et al.	3/3/1981	
		4,687,559		Coburn et al.	8/18/1987	
		5,510,040		Miller et al.	4/23/1996	
		5,071,568		Bennett et al.	12/10/1991	

**OTHER INFORMATION - NON PATENT LITERATURE DOCUMENTS**

Examiner Initials	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T <sup>2</sup>
		International Search Report	
		SHIN'ICHI KURANOUCI ET AL., "Study of One-Step Electrodeposition Condition for Preparation of CuIn(Se, S) <sub>2</sub> Thin Films", <u>Solar Energy Materials and Solar Cells</u> 50, (1998), pp. 31-36.	
		GUILLEN ET AL., "Cathodic Electrodeposition of CuInSe <sub>2</sub> Thin Films", <u>Thin Solid Films</u> , 195(1991) January, pp. 137-146, Nos. 1/2, Lausanne, CH	
		NAKAMURA ET AL., "Composition Control of Electrodeposited Cu-In-Se Layers for Thin Film CuInSe <sub>2</sub> Preparation", <u>Solar Energy Materials and Solar Cells</u> 50, (1998), pp. 25-30.	

Examiner Signature		Date Considered	
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<sup>1</sup>Unique citation designation number. <sup>2</sup>Applicant is to place a check mark here if English language translation is attached.